

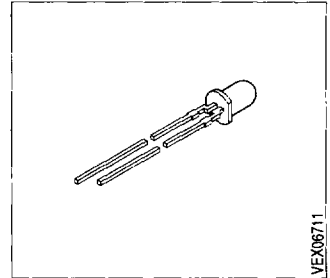
3 mm (T1) LED, Diffused Super-Bright, Hyper-Red GaAlAs-LED

Besondere Merkmale

- eingefärbtes, diffuses Gehäuse
- Doppel-Heterostruktur in GaAlAs Technologie
- besonders hohe Lichtstärke
- Lötspieße mit Aufsetzebene
- gegurtet lieferbar
- Störimpulstest nach DIN 40839

Features

- colored, diffused package
- double heterojunction in GaAlAs technology
- especially high luminous intensity
- solder leads with stand-off
- available taped on reel
- load dump resistant acc. to DIN 40839



Typ Type	Emissionsfarbe Color of Emission	Gehäusefarbe Color of Package	Lichtstärke Luminous Intensity $I_F = 10 \text{ mA}$ I_V (mcd)	Bestellnummer Ordering Code
LH 3364-LP	hyper-red	red diffused	10 ... 80	Q62703-Q3202
LH 3364-M			16 ... 32	Q62703-Q3203
LH 3364-N			25 ... 50	Q62703-Q2798
LH 3364-MQ			16 ... 125	Q62703-Q3201

Streuung der Lichtstärke in einer Verpackungseinheit $I_{V \max} / I_{V \min} \leq 2.0$.
Luminous intensity ratio in one packaging unit $I_{V \max} / I_{V \min} \leq 2.0$.

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Werte Values	Einheit Unit
Betriebstemperatur Operating temperature range	T_{00}	- 55 ... + 100	°C
Lagertemperatur Storage temperature range	T_{stg}	- 55 ... + 100	°C
Sperrschichttemperatur Junction temperature	T_j	+ 100	°C
Durchlaßstrom Forward current	I_F	40	mA
Stoßstrom Surge current $t \leq 10 \mu s, D = 0.005$	I_{FM}	0.5	A
Sperrspannung Reverse voltage	V_R	3	V
Verlustleistung Power dissipation $T_A \leq 25 \text{ °C}$	P_{tot}	120	mW
Wärmewiderstand Thermal resistance Sperrschicht / Luft Junction / air	$R_{th,JA}$	400	K/W

Kennwerte ($T_A = 25\text{ °C}$)

Characteristics

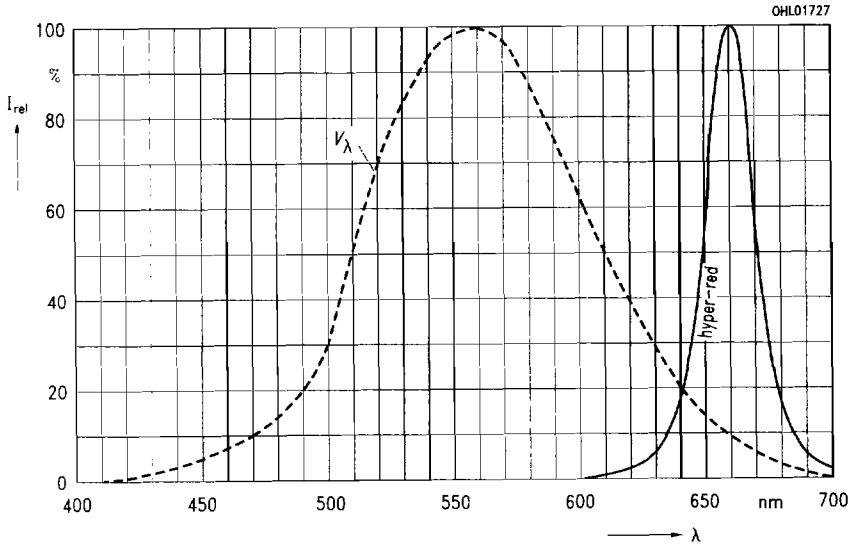
Bezeichnung Parameter	Symbol Symbol	Werte Values	Einheit Unit
Wellenlänge des emittierten Lichtes Wavelength at peak emission $I_F = 20\text{ mA}$	(typ.) λ_{peak} (typ.)	660	nm
Dominantwellenlänge Dominant wavelength $I_F = 20\text{ mA}$	(typ.) λ_{dom} (typ.)	645	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 20\text{ mA}$	(typ.) $\Delta\lambda$ (typ.)	22	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) Viewing angle at 50 % I_V	2φ	45	Grad deg.
Durchlaßspannung Forward voltage $I_F = 10\text{ mA}$	(typ.) V_F (max.) V_F	1.75 2.6	V V
Sperrstrom Reverse current $V_R = 3\text{ V}$	(typ.) I_R (max.) I_R	0.01 10	μA μA
Kapazität Capacitance $V_R = 0\text{ V}, f = 1\text{ MHz}$	(typ.) C_0	25	pF
Schaltzeiten: Switching times:			
I_V from 10 % to 90 %	(typ.) t_r	140	ns
I_V from 90 % to 10 % $I_F = 100\text{ mA}, t_p = 10\text{ }\mu\text{s}, R_L = 50\text{ }\Omega$	(typ.) t_i	110	ns

Relative spektrale Emission $I_{rel} = f(\lambda)$, $T_A = 25\text{ }^\circ\text{C}$, $I_F = 20\text{ mA}$

Relative spectral emission

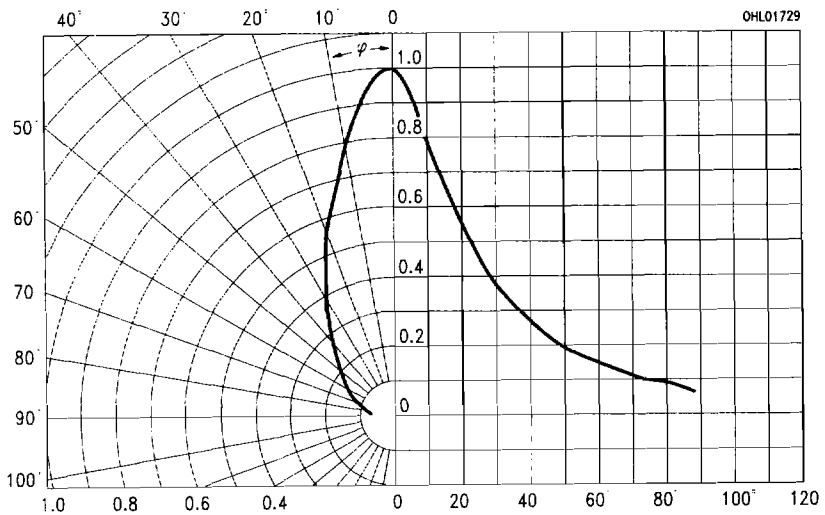
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



Abstrahlcharakteristik $I_{rel} = f(\varphi)$

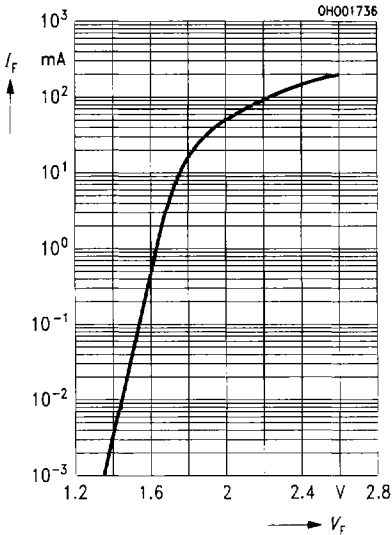
Radiation characteristic



Durchlaßstrom $I_F = f(V_F)$

Forward current

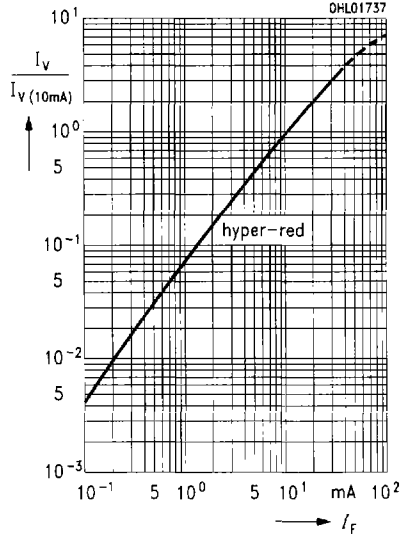
$T_A = 25^\circ\text{C}$



Relative Lichtstärke $I_V/I_{V(10\text{mA})} = f(I_F)$

Relative luminous intensity

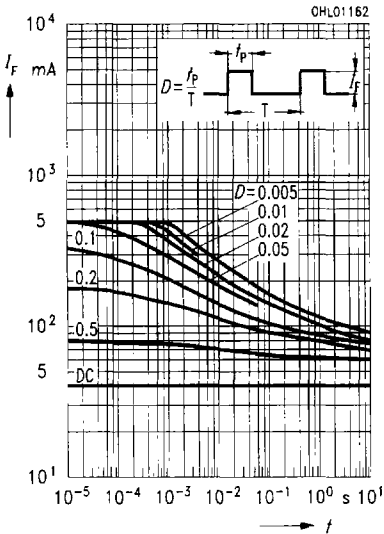
$T_A = 25^\circ\text{C}$



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$

Permissible pulse handling capability

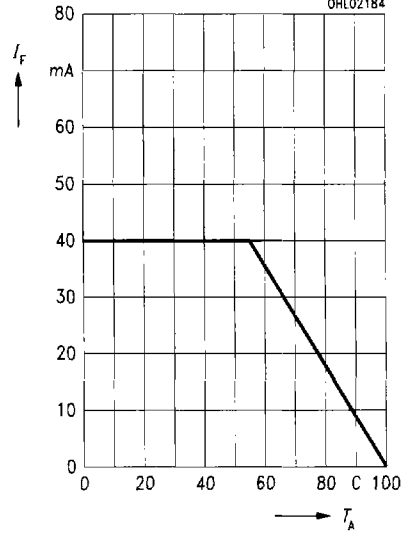
Duty cycle $D =$ parameter, $T_A = 25^\circ\text{C}$



Maximal zulässiger Durchlaßstrom

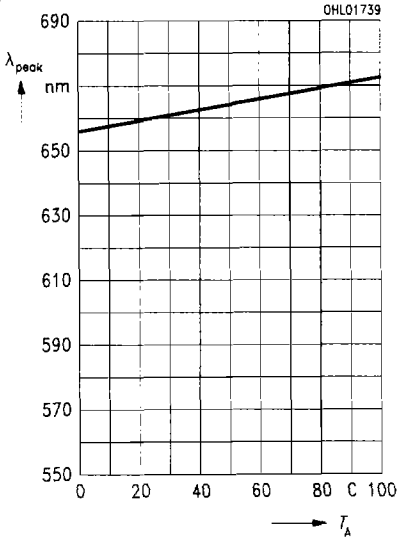
Max. permissible forward current

$I_F = f(T_A)$



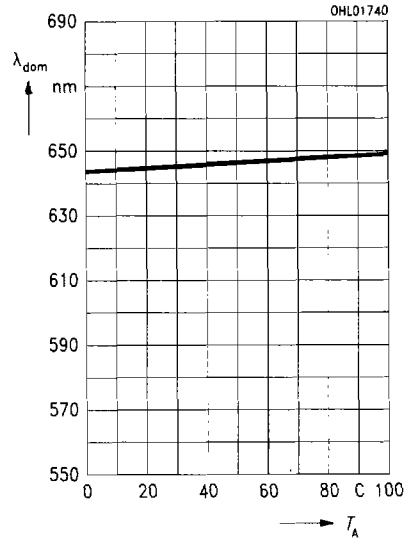
Wellenlänge der Strahlung $\lambda_{\text{peak}} = f(T_A)$
Wavelength at peak emission

$I_F = 20 \text{ mA}$



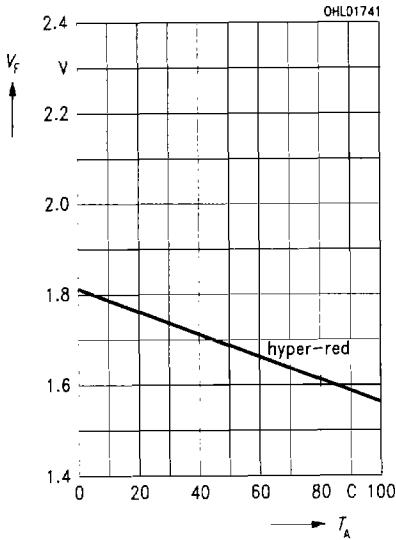
Dominantwellenlänge $\lambda_{\text{dom}} = f(T_A)$
Dominant wavelength

$I_F = 20 \text{ mA}$



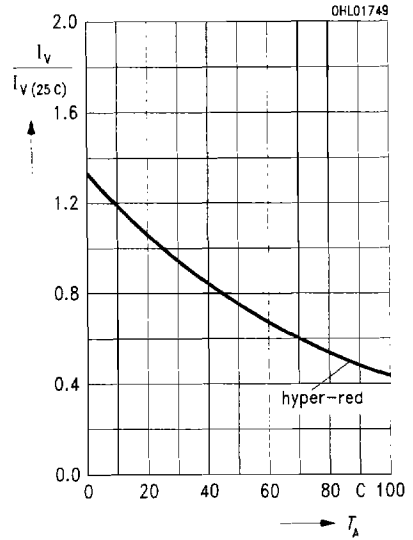
Durchlaßspannung $V_F = f(T_A)$
Forward voltage

$I_F = 10 \text{ mA}$

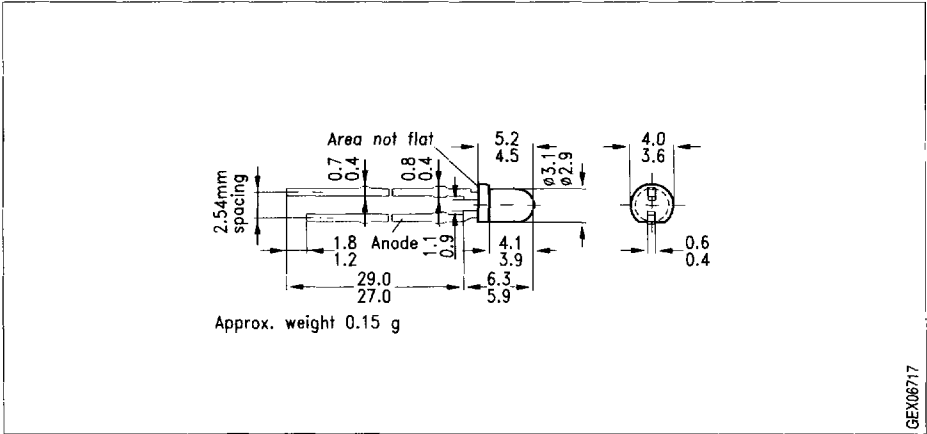


Relative Lichtstärke $I_V/I_{V(25^\circ\text{C})} = f(T_A)$
Relative luminous intensity

$I_F = 10 \text{ mA}$



Maßzeichnung (Maße in mm, wenn nicht anders angegeben)
Package Outlines (Dimensions in mm, unless otherwise specified)



Anodenkennzeichnung: Kürzerer Lötspieß
Anode mark: Short solder lead